



## Exploring the phase-diagram of molecular crystals during ultrafast photo-induced non-equilibrium dynamics

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## Acknowledgments





#### **Materials & Light team**

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![](_page_2_Picture_0.jpeg)

![](_page_2_Picture_1.jpeg)

![](_page_2_Picture_2.jpeg)

#### Ultrafast photo-induced dynamics of materials

- Goal 
  beyond the sole use of temperature as external thermodynamical control parameter
- Exploring the Pressure Temperature Phase Diagram of Molecular Material
- Seek for peculiar the Photo-Induced Dynamics in well defined parts of the Phase Diagram

![](_page_3_Picture_0.jpeg)

## **Optical Setup**

![](_page_3_Picture_2.jpeg)

![](_page_3_Figure_3.jpeg)

![](_page_3_Figure_4.jpeg)

Supercontinuum/White light Spectroscopy

- (470-750 nm)
- Time resolution ~ 100 fs
- Sensitivity ~ 0.1 mOD (10<sup>-4</sup>)
- Pump (450-2200 nm) → 800 nm

With courtesy of G. Azzolina

## **High Pressure Setup**

Already used in pump-probe experiments with diamond anvil cell (lesser control)

![](_page_4_Figure_2.jpeg)

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o-7 kbars (o-o.7 Gpa) 10-300 K 250-5000 nm

Multi-stages He gas based cell

Specifications:

- Precision of few bars (measure in operando)
- Ramping up/down of few bars per minutes
- Sapphire windows allowing optical Transmission/Reflection

## **High Pressure Setup**

Already used in pump-probe experiments with diamond anvil cell (lesser control)

![](_page_5_Figure_2.jpeg)

Multi-stages He gas based cell

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250-5000 nm

Specifications:

- Precision of few bars (measure in operando)
- Ramping up/down of few bars per minutes •
- Sapphire windows allowing optical Transmission/Reflection ٠

## V<sub>2</sub>O<sub>3</sub> Phase Diagram

Creater

First a "*counter"* example: V2O3  $\implies$  Benchmark of Mott physics

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![](_page_6_Figure_3.jpeg)

- Pure V2O3 without chemical substitution is a Paramagnetic "bad" Metal (PM) under standard thermodynamical conditions
- No expected phase transition under hydrostatic pressure
- Thin film of ~ 190 nm thickness

Inorganic materials  $\implies$  needs of several GPa (ten's of kbars)

D. B. McWhan et al , *Phys. Rev. B* , 7, 1920-1931 (1973)

![](_page_7_Figure_1.jpeg)

![](_page_7_Figure_2.jpeg)

Pump 800 nm

![](_page_8_Figure_1.jpeg)

![](_page_8_Figure_2.jpeg)

G. Huitric et al, Faraday Discussion (2022)

G. Privault et al, *submitted* 

![](_page_9_Picture_1.jpeg)

#### Reflectivity

![](_page_9_Figure_3.jpeg)

Pump 800 nm

![](_page_10_Figure_1.jpeg)

![](_page_10_Figure_2.jpeg)

![](_page_11_Figure_1.jpeg)

#### **Phonon potential**

![](_page_12_Figure_2.jpeg)

No apparent shift in  $A_{1q}$  frequency

No observable modification of the  $A_{1q}$  phonon potential (o-6 kbars)

![](_page_13_Figure_1.jpeg)

Normalized transient transmission at 650 nm

Shift of the rising time and oscillations (arrows) related to strain propagation effect:

Impact on speed of sound

#### **Acoustic properties**

![](_page_14_Figure_2.jpeg)

#### Blue shift of the "Brillouin" frequency under pressure Increase of speed of sound / stiffening

Even in inorganic V2O3, pressure below GPa acts on acoustic properties: may impact photo-induced strain effects

![](_page_15_Picture_0.jpeg)

# CINIC

#### MOC: Molecular Conductors

![](_page_15_Figure_4.jpeg)

![](_page_16_Picture_0.jpeg)

![](_page_16_Picture_2.jpeg)

System displaying Metal to Insulator (MIT) Phase Transition

![](_page_16_Figure_4.jpeg)

#### Low Temperature Phase

![](_page_16_Figure_6.jpeg)

![](_page_17_Picture_0.jpeg)

# Tentative Phase Diagram of (EDO-TTF)-XF<sub>6</sub>

![](_page_17_Picture_2.jpeg)

#### 1<sup>st</sup> Order Phase Transition

![](_page_17_Figure_4.jpeg)

M. Maesato et al, J. of Phys.: Conference Series 148 (1), 012004, (2009)

![](_page_18_Picture_0.jpeg)

40

30

a)

![](_page_18_Figure_1.jpeg)

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![](_page_18_Figure_2.jpeg)

Related to the collapse of electronic charge order.

Strongly related to atomic structure as coherent phonons modulate reflectivity up to 10 %

**AR/R** (%) 20 10 0 -2 0 2 4 6 Time (ps) 1.0 i) 0.8 0.6 0.4 0.2

0.0

M. Servol et al, *Phys. Rev. B*, 92(2) 024304 (2015)

3

Frequency (THz)

2

rontières

pump=1.46 eV

probe=1.72 eV

230 K

230 K

5

8

M. Chollet et al, Science, 307 (5706) 86 (2005)

![](_page_19_Picture_0.jpeg)

### Ambient Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

# 

#### Pump 800 nm

![](_page_19_Figure_4.jpeg)

![](_page_19_Picture_5.jpeg)

Broadband reflectivity changes after 800 nm pumping

![](_page_20_Picture_0.jpeg)

### Ambient Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

CI

#### Pump 800 nm

![](_page_20_Figure_3.jpeg)

800 nm pumping

![](_page_21_Picture_0.jpeg)

### Ambient Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

Culticas

#### Transient reflectivity at 660 nm

![](_page_21_Figure_3.jpeg)

Model with bi-exponential decay:

- 250 fs, electron-electron?
- 1.3 ps, electron-phonon?

**Relaxation of excited carriers** 

![](_page_22_Picture_0.jpeg)

# High Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

#### picosecond timescale / 3000 bars

![](_page_22_Figure_3.jpeg)

Broadband reflectivity changes after 800 nm pumping

![](_page_23_Picture_0.jpeg)

### High Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

![](_page_23_Figure_2.jpeg)

800 nm pumping

![](_page_23_Figure_4.jpeg)

![](_page_24_Picture_0.jpeg)

# High Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

![](_page_24_Figure_2.jpeg)

FFT at several wavelengths:

L'antières

- Observation of several modes (1THz, 2THz)
  - Match the thermally driven case

![](_page_24_Figure_6.jpeg)

![](_page_25_Picture_0.jpeg)

# High Pressure P-I dynamics in (EDO-TTF)-XF<sub>6</sub>

![](_page_25_Figure_2.jpeg)

E // to stacking axis

 $E \perp to stacking axis$ 

anisotropic response expected for 1 D conductors

![](_page_26_Picture_0.jpeg)

acoustic timescale / 1 bar

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![](_page_26_Picture_2.jpeg)

Broadband reflectivity changes after 800 nm pumping

## Time Dependent Brillouin Scattering in (EDO-TTF)-XF<sub>6</sub>

![](_page_27_Figure_1.jpeg)

Broadband reflectivity changes after 800 nm pumping

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T. Parpiiev et al , *Appl. Phys. Lett.* , 111, 151901 (2017)

### Time Dependent Brillouin Scattering in (EDO-TTF)-XF<sub>6</sub>

![](_page_28_Figure_1.jpeg)

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Broadband reflectivity changes after 800 nm pumping

![](_page_28_Figure_3.jpeg)

Increase of Brillouin frequency F<sub>B</sub>:

• 5.5 GHz (1 bar) to 15 GHz (5500 bars)

## **Photo-induced strain effects**

![](_page_29_Picture_1.jpeg)

Article | Open Access | Published: 23 February 2021

Strain wave pathway to semiconductor-to-metal transition revealed by time-resolved X-ray powder diffraction

![](_page_29_Figure_4.jpeg)

Acoustic/strain processes might be relevant in the establishment of a new macroscopic phase and likely to occur in the 10 to 100 ps timescale

T. Ishikawa et al , *Crystals*, 2(3), 1067 (2012)

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C. Mariette et al , *Nat Com*, 12(1), 1-11 (2021)

![](_page_30_Picture_0.jpeg)

![](_page_30_Picture_2.jpeg)

- Broadand ultrafast optical spectroscopy under high pressure (o-6kbars)
- Time resolution as good as ~100 fs
- Observation of coherent optical phonons and thermo-elastic processes
- Strong modification of (v/n) in molecular materials